TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74VHC14F, TC74VHC14FN, TC74VHC14FT

#### HEX SCHMITT **INVERTER**

The TC74VHC14 is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate C2MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

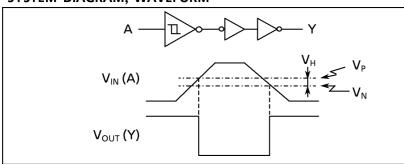
Pin configuration and function are the same as the TC74VHC04 but the inputs have hysteresis and with its schmitt trigger function, the TC74VHC14 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

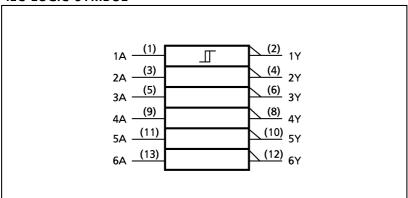
#### FEATURES:

- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays  $\cdots t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range  $\cdots$   $V_{CC}$  (opr) =  $2V \sim 5.5V$
- Low Noise ......V<sub>OLP</sub> = 0.8V (Max.)
- Pin and Function Compatible with 74ALS14

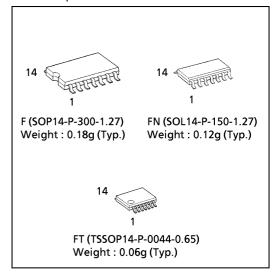
#### SYSTEM DIAGRAM, WAVEFORM



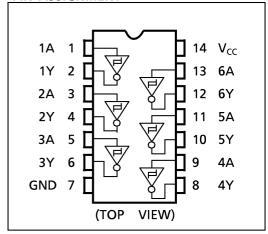
#### **IEC LOGIC SYMBOL**



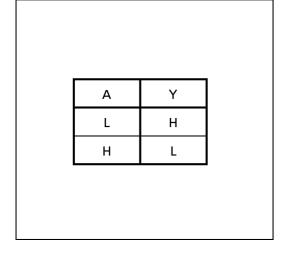
(Note) The JEDEC SOP (FN) is not available in Japan.



#### **PIN ASSIGNMENT**



#### TRUTH TABLE



# **ABSOLUTE MAXIMUM RATINGS**

| PARAMETER                          | SYMBOL                | VALUE                    | UNIT |
|------------------------------------|-----------------------|--------------------------|------|
| Supply Voltage Range               | $V_{cc}$              | -0.5~7.0                 | V    |
| DC Input Voltage                   | VIN                   | -0.5~7.0                 | V    |
| DC Output Voltage                  | V <sub>OUT</sub>      | $-0.5 \sim V_{CC} + 0.5$ | V    |
| Input Diode Current                | I <sub>IK</sub>       | <b>-20</b>               | mA   |
| Output Diode Current               | I <sub>OK</sub>       | ± 20                     | mA   |
| DC Output Current                  | I <sub>OUT</sub>      | ± 25                     | mA   |
| DC V <sub>CC</sub> /Ground Current | I <sub>cc</sub>       | ± 50                     | mA   |
| Power Dissipation                  | <b>P</b> <sub>D</sub> | 180                      | mW   |
| Storage Temperature                | T <sub>stg</sub>      | <b>−65~150</b>           | °C   |

# **RECOMMENDED OPERATING CONDITIONS**

| PARAMETER             | SYMBOL           | VALUE             | UNIT        |
|-----------------------|------------------|-------------------|-------------|
| Supply Voltage        | $V_{cc}$         | 2.0~5.5           | <b>&gt;</b> |
| Input Voltage         | V <sub>IN</sub>  | 0~5.5             | V           |
| Output Voltage        | V <sub>OUT</sub> | 0~V <sub>cc</sub> | ٧           |
| Operating Temperature | T <sub>opr</sub> | <b>−40~85</b>     | °C          |

# DC ELECTRICAL CHARACTERISTICS

| PARAMETER                      | SYMBOL           | TEST CONDITION                    |                                 | V <sub>cc</sub>      | Ta = 25°C            |                      |                      | Ta = - 4             | a = −40~85°C         |            |
|--------------------------------|------------------|-----------------------------------|---------------------------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|------------|
| PARAIVIETER                    | STIVIBUL         |                                   |                                 | (V)                  | MIN.                 | TYP.                 | MAX.                 | MIN.                 | MAX.                 | UNIT       |
| Positive Threshold<br>Voltage  | V <sub>P</sub>   |                                   | 3.0<br>4.5<br>5.5               | 111                  | 111                  | 2.20<br>3.15<br>3.85 | _<br>_<br>_          | 2.20<br>3.15<br>3.85 | ٧                    |            |
| Negative Threshold<br>Voltage  | V <sub>N</sub>   |                                   | 3.0<br>4.5<br>5.5               | 0.90<br>1.35<br>1.65 | 1 1 1                | _<br>_<br>_          | 0.90<br>1.35<br>1.65 | _<br>_<br>_          | <                    |            |
| Hysteresis Voltage             | V <sub>H</sub>   |                                   |                                 | 3.0<br>4.5<br>5.5    | 0.30<br>0.40<br>0.50 | 111                  | 1.20<br>1.40<br>1.60 | 0.30<br>0.40<br>0.50 | 1.20<br>1.40<br>1.60 | >          |
| High - Level<br>Output Voltage | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IL</sub> | $I_{OH} = -50\mu A$             | 2.0<br>3.0<br>4.5    | 1.9<br>2.9<br>4.4    | 2.0<br>3.0<br>4.5    | _<br>_<br>_          | 1.9<br>2.9<br>4.4    | _<br>_<br>_          | >          |
|                                |                  |                                   | $I_{OH} = -4mA$ $I_{OH} = -8mA$ | 3.0<br>4.5           | 2.58<br>3.94         | 1 1                  | _<br>_               | 2.48<br>3.80         | _                    |            |
| Low - Level<br>Output Voltage  | V <sub>o L</sub> | V <sub>IN</sub> = V <sub>IH</sub> | $I_{OL} = 50 \mu A$             | 2.0<br>3.0<br>4.5    | 111                  | 0.0<br>0.0<br>0.0    | 0.1<br>0.1<br>0.1    | _<br>_<br>_          | 0.1<br>0.1<br>0.1    | <          |
|                                |                  |                                   | $I_{OL} = 4mA$ $I_{OL} = 8mA$   | 3.0<br>4.5           | 1 1                  | 1 1                  | 0.36<br>0.36         | _                    | 0.44<br>0.44         |            |
| Input Leakage Current          | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5V or GND     |                                 | 0~5.5                | 1                    | ı                    | ± 0.1                | _                    | ± 1.0                |            |
| Quiescent Supply Current       | I <sub>cc</sub>  | $V_{IN} = V_{CC}$ or GND          |                                 | 5.5                  | _                    | _                    | 2.0                  | _                    | 20.0                 | μ <b>A</b> |

| AC E | LECTRICAL | <b>CHARACTERISTICS</b> | (Input | $t_r = t_f = 3ns$ ) |
|------|-----------|------------------------|--------|---------------------|
|------|-----------|------------------------|--------|---------------------|

| PARAMETER                     | SYMBOL                               | TEST CONDITION |                     | Ta = 25°C |      |      | Ta = - 40~85°C |      | UNIT |      |
|-------------------------------|--------------------------------------|----------------|---------------------|-----------|------|------|----------------|------|------|------|
|                               |                                      |                | V <sub>CC</sub> (V) | CL (pF)   | MIN. | TYP. | MAX.           | MIN. | MAX. | UNIT |
| Propagation Delay Time        | t <sub>pLH</sub><br>t <sub>pHL</sub> |                | 3.3 ± 0.3           | 15        | _    | 8.3  | 12.8           | 1.0  | 15.0 |      |
|                               |                                      |                |                     | 50        | _    | 10.8 | 16.3           | 1.0  | 18.5 |      |
|                               |                                      |                | 5.0 ± 0.5           | 15        | _    | 5.5  | 8.6            | 1.0  | 10.0 | ns   |
|                               |                                      |                | 3.0 ± 0.3           | 50        | _    | 7.0  | 10.6           | 1.0  | 12.0 |      |
| Input Capacitance             | C <sub>I N</sub>                     |                |                     |           | _    | 4    | 10             | _    | 10   |      |
| Power Dissipation Capacitance | C <sub>PD</sub>                      |                | (Note 1)            |           | _    | 21   | _              | _    | _    | pF   |

Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

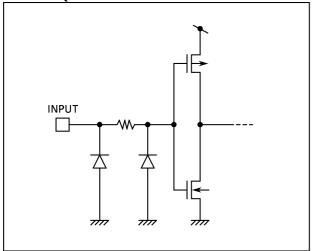
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (per Gate)}$ 

# NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$ )

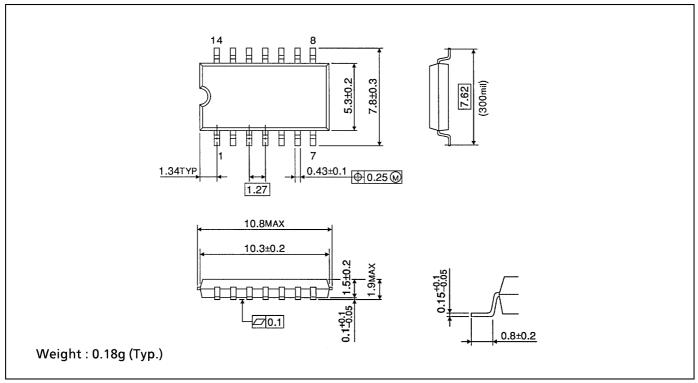
| PARAMETER                                       | CVAROL           | TEST CONDIT           | Ta =                | LINUT |       |      |
|---|------------------|-----------------------|---------------------|-------|-------|------|
| PARAIVIETER                                     | SYMBOL           |                       | V <sub>CC</sub> (V) | TYP.  | LIMIT | UNIT |
| Quiet Output<br>Maximum Dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50pF | 5.0                 | 0.4   | 0.8   | <    |
| Quiet Output<br>Minimum Dynamic V <sub>OL</sub> | V <sub>OLV</sub> | $C_L = 50pF$          | 5.0                 | -0.4  | -0.8  | \ \  |
| Minimum High Level<br>Dynamic Input Voltage     | V <sub>IHD</sub> | $C_L = 50pF$          | 5.0                 | ı     | 3.5   | >    |
| Maximum Low Level<br>Dynamic Input Voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50pF | 5.0                 | _     | 1.5   | V    |

# INPUT EQUIVALENT CIRCUIT



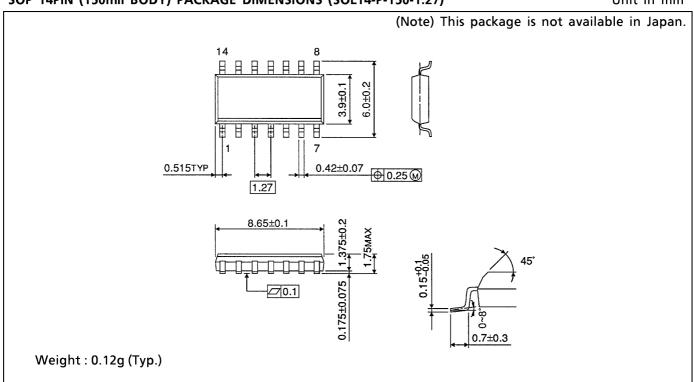
# SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm



# SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150-1.27)

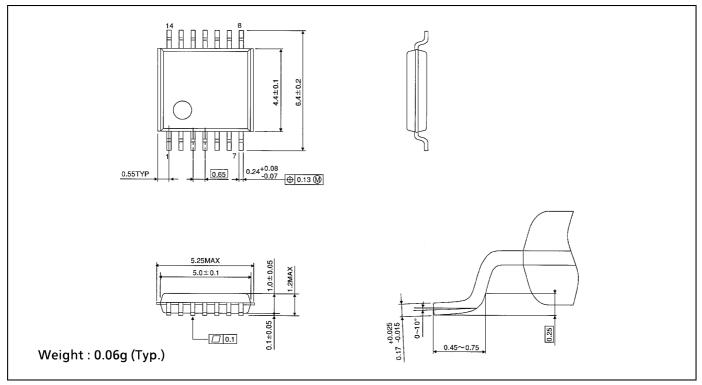
Unit in mm



4

# TSSOP 14PIN PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)

Unit in mm



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